

PS9124

R08DS0049EJ0100

Rev.1.00

HIGH CMR, 10 Mbps OPEN COLLECTOR OUTPUT TYPE, 5-PIN SOP (SO-5) PHOTOCOUPLER

Aug 30, 2013

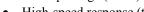
DESCRIPTION

The PS9124 is an optically coupled high-speed, active low type isolator containing a GaAlAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

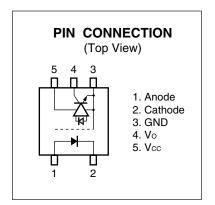
FEATURES

<R>

- Low power consumption ($V_{CC} = 3.3/5 \text{ V}$)
- Small package (SO-5)



- High-speed response ($t_{PHL} = 100 \text{ ns MAX.}$, $t_{PLH} = 100 \text{ ns MAX.}$)
- High-speed (10 Mbps)
- High isolation voltage (BV = 3 750 Vr.m.s.)
- Open collector output
- Embossed tape product: PS9124-F3 : 2 500 pcs/reel
- · Pb-Free product
- · Safety standards
 - UL approved: No. E72422
 - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
 - DIN EN 60747-5-5 (VDE 0884-5) approved (Option)

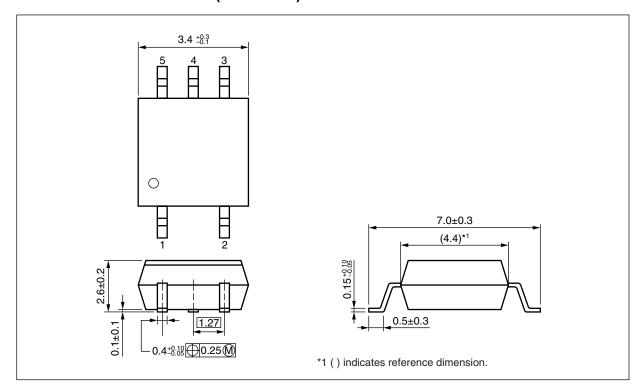


APPLICATIONS <R>

• FA Network

The mark <R> shows major revised points.

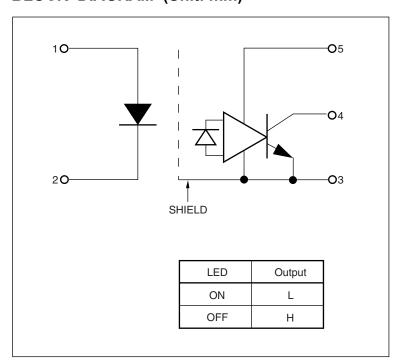
PACKAGE DIMENSIONS (UNIT: mm)



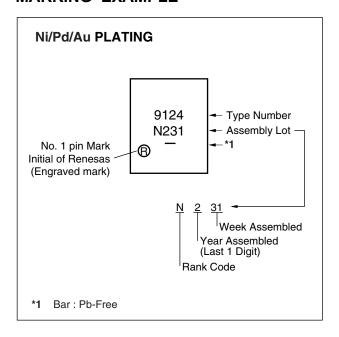
PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	4.2 mm
Outer Creepage Distance	4.2 mm
Isolation Distance	0.2 mm

BLOCK DIAGRAM (Unit: mm)



MARKING EXAMPLE



ORDERING INFORMATION

Part Number	Order Number	Solder Plating	Packing Style	Safety Standards	Application
		Specification		Approval	Part Number *1
PS9124	PS9124-AX	Pb-Free	20 pcs (Tape 20 pcs cut)	Standard products	PS9124
PS9124-F3	PS9124-F3-AX	(Ni/Pd/Au)	Embossed Tape 2 500	(UL, CSA	
			pcs/reel	approved)	
PS9124-V	PS9124-V-AX		20 pcs (Tape 20 pcs cut)	DIN EN60747-5-5	
PS9124-V-F3	PS9124-V-F3-AX		Embossed Tape 2 500	(VDE0884-5)	
			pcs/reel	approved (Option)	

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current *1	I _F	25	mA
	Reverse Voltage	V_R	5	V
Detector	Supply Voltage	V _{CC}	7	V
	Output Voltage	Vo	7	V
	Output Current	Io	25	mA
	Power Dissipation *2		200	mW
Isolation Voltage *3		BV	3 750	Vr.m.s.
Operating Ambient Temperature		T _A	-40 to +110	°C
Storage Temperature		T_{stg}	-55 to +125	°C

Notes: *1. Reduced to 0.2 mA/ $^{\circ}$ C at T_A = 25 $^{\circ}$ C or more.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Low Level Input Voltage	V_{FL}	-2		0.8	V
High Level Input Current	I _{FH}	3.8	6.0	7.5	mA
Supply Voltage	V_{CC}	2.7	3.3	3.6	V
		4.5	5.0	5.5	
TTL ($R_L = 1 \text{ k}\Omega$, loads)	N			5	
Pull-up Resistor	R_L	330		4 k	Ω

^{*2.} Reduced to 4.0 mW/°C at $T_A = 75$ °C or more.

^{*3} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-2 shorted together, 3-5 shorted together.

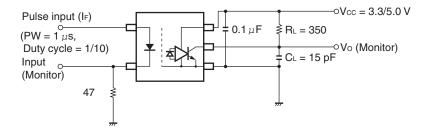
ELECTRICAL CHARACTERISTICS ($T_A = -40$ to +110°C, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP. *1	MAX.	Unit
Diode	Forward Voltage	V_{F}	I _F = 10 mA, T _A = 25°C	1.3	1.55	1.8	V
	Reverse Current	I _R	V _R = 3 V, T _A = 25°C			10	μΑ
	Terminal Capacitance	Ct	$f = 1 \text{ MHz}, V_F = 0 \text{ V}, T_A = 25^{\circ}\text{C}$		30		pF
Detector	High Level Output Current	I _{OH}	$V_{CC} = V_O = 3.3 \text{ V}, V_F = 0.8 \text{ V}$		1	80	μΑ
			$V_{CC} = V_O = 5.5 \text{ V}, V_F = 0.8 \text{ V}$		1	100	
	Low Level Output Voltage	V _{OL}	$V_{CC} = 3.3 \text{ V}, I_F = 4.5 \text{ mA},$		0.2	0.6	V
			I _{OL} = 13 mA				
			$V_{CC} = 5.5 \text{ V}, I_F = 4.5 \text{ mA},$				
			I _{OL} = 13 mA				
	High Level Supply Current	I _{CCH}	$V_{CC} = 3.3 \text{ V}, I_F = 0 \text{ mA},$		4	7	mA
			V _O = open				
			$V_{CC} = 5.5 \text{ V}, I_F = 0 \text{ mA},$				
			V _O = open				
	Low Level Supply Current	I _{CCL}	$V_{CC} = 3.3 \text{ V}, I_F = 4.5 \text{ mA},$		6	10	mA
			V _O = open				
			$V_{CC} = 5.5 \text{ V}, I_F = 4.5 \text{ mA},$		7	10	
		_	V _O = open				
Coupled	Threshold Input Voltage	I _{FHL}	$V_{CC} = 3.3 \text{ V}, R_L = 350 \Omega,$		1.0	3.0	mA
	$(H \rightarrow L)$		V _O = 0.8 V				
			$V_{CC} = 5 \text{ V}, R_L = 350 \Omega,$				
	Indiation Designation		V _O = 0.8 V	10 ¹¹			-
	Isolation Resistance	R _{I-O}	$V_{I-O} = 1 \text{ kV}_{DC}$, RH = 40 to 60%,	10			Ω
	Isolation Capacitance	C _{I-O}	$T_A = 25^{\circ}C$ V = 0 V, f = 1 MHz, $T_A = 25^{\circ}C$		0.6		pF
	Propagation Delay Time		$T_A = 25^{\circ}C$		40	75	ns
	$(H \rightarrow L)^{*2}$	t _{PHL}	$V_{CC} = 3.3 \text{ V}, I_{E} = 4.5 \text{ mA},$		40	100	115
	$(\Pi \rightarrow L)$		$R_L = 350 \Omega, C_L = 15 pF$			100	
			T _A = 25°C		40	75	
			$V_{CC} = 5 \text{ V}, I_F = 4.5 \text{ mA},$		10	100	
			$R_L = 350 \Omega, C_L = 15 pF$			100	
	Propagation Delay Time	t _{PLH}	T _A = 25°C		50	75	ns
	$(L \rightarrow H)^{*2}$	YFLN	$V_{CC} = 3.3 \text{ V}, I_{E} = 4.5 \text{ mA},$			100	110
	(L → 11)		$R_L = 350 \Omega, C_L = 15 pF$			100	
			T _A = 25°C		45	75	
			$V_{CC} = 5 \text{ V}, I_F = 4.5 \text{ mA},$		10	100	
			$R_L = 350 \Omega, C_L = 15 pF$			100	
	Pulse Width Distortion	t _{PHL-} t _{PLH}	$V_{CC} = 3.3/5 \text{ V}, I_F = 4.5 \text{ mA},$		5	35	ns
	(PWD)	TYPHL-YPLH I	$R_L = 350 \Omega, C_L = 15 pF$				1.0
	Propagation Delay Skew	t _{psk}	$V_{CC} = 3.3/5 \text{ V}, I_F = 4.5 \text{ mA},$			40	ns
	.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	Poix	$R_L = 350 \Omega$, $C_L = 15 pF$				
	Rise Time	t _r	$V_{CC} = 3.3/5 \text{ V}, I_F = 4.5 \text{ mA},$		20		ns
			$R_L = 350 \Omega, C_L = 15 pF$				
	Fall Time	t _f	$V_{CC} = 3.3/5 \text{ V}, I_F = 4.5 \text{ mA},$		5		ns
			R_L = 350 Ω , C_L = 15 pF				
	Common Mode	CM _H	V _{CC} = 3.3/5 V, T _A = 25°C,	10	15		kV/μs
	Transient Immunity at		$I_F = 0 \text{ mA}, V_O > 2 \text{ V},$				
	High Level Output *3		$R_L = 350 \Omega$, $V_{CM} = 1 kV$				
	Common Mode	CM∟	$V_{CC} = 3.3/5 \text{ V}, T_A = 25^{\circ}\text{C},$	10	15		kV/ <i>μ</i> s
	Transient Immunity at Low		$I_F = 4.5 \text{ mA}, V_O < 0.8 \text{ V},$				
	Level Output *3		$R_L = 350 \Omega$, $V_{CM} = 1 \text{ kV}$				

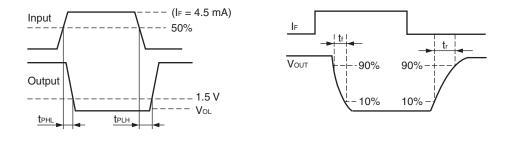
Notes: *1. Typical values at $T_A = 25^{\circ}C$

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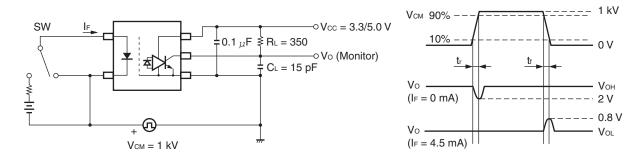
*2. Test circuit for propagation delay time



 $\textbf{Remark} \quad \textbf{C}_{\scriptscriptstyle L} \text{ includes probe and stray wiring capacitance}.$

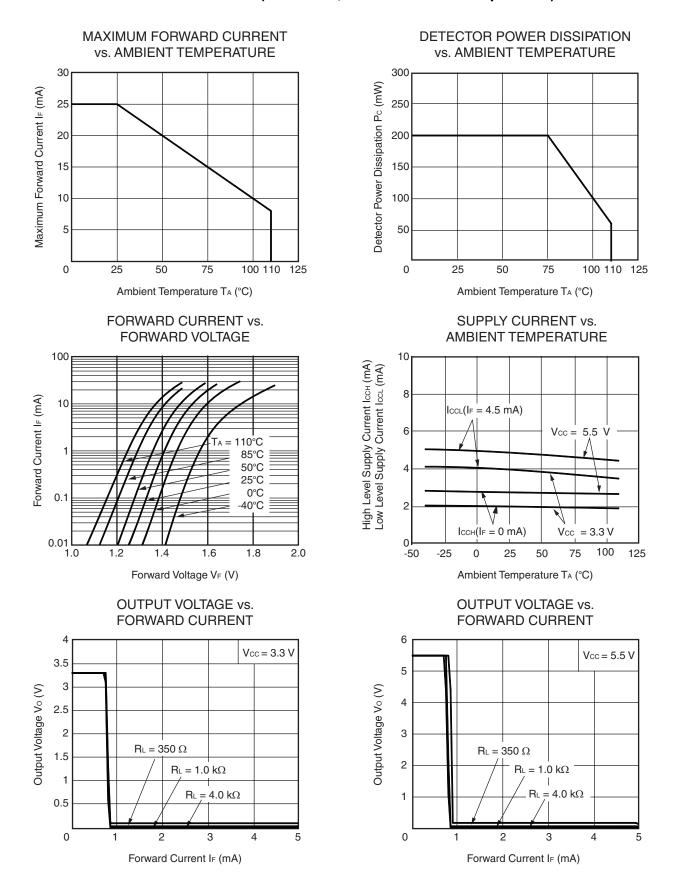


*3. Test circuit for common mode transient immunity

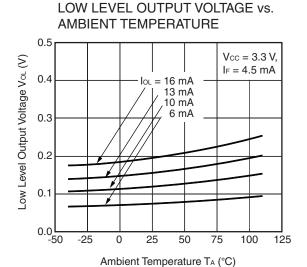


Remark C_i includes probe and stray wiring capacitance.

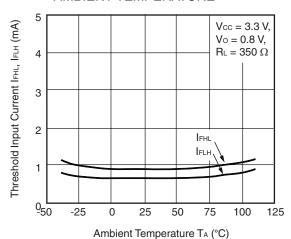
<R> TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



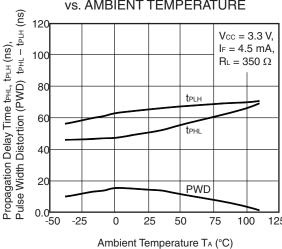
Remark The graphs indicate nominal characteristics.



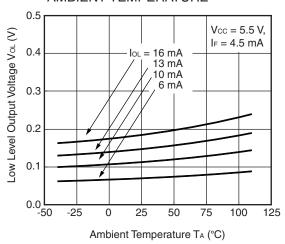
THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE



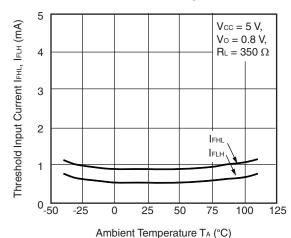
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE



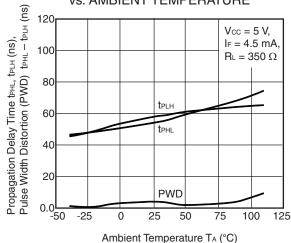
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE

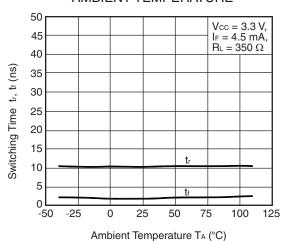


PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE

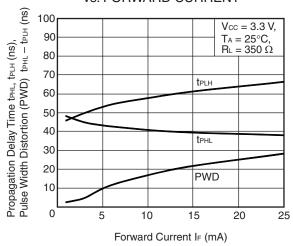


Remark The graphs indicate nominal characteristics.

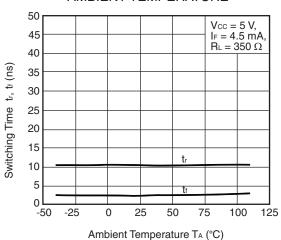
SWITCHING TIME vs. AMBIENT TEMPERATURE



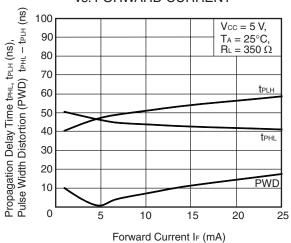
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. FORWARD CURRENT



SWITCHING TIME vs. AMBIENT TEMPERATURE

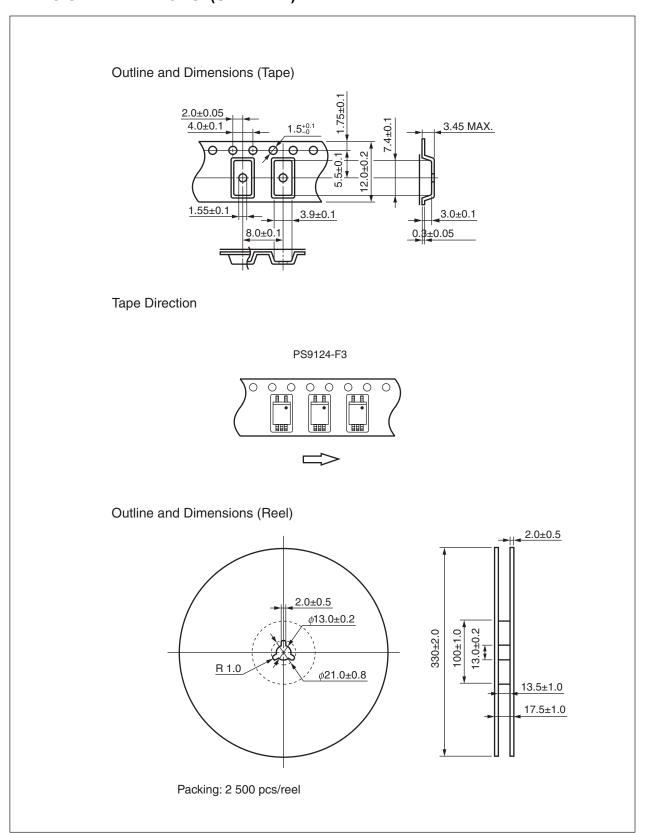


PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. FORWARD CURRENT

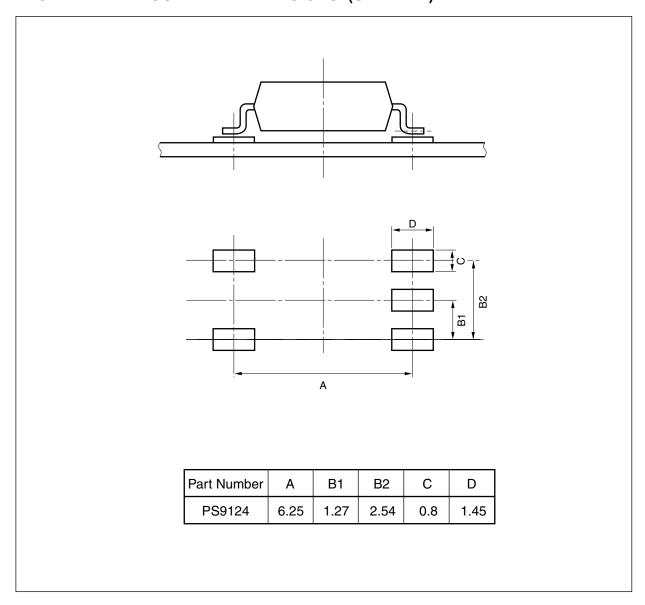


Remark The graphs indicate nominal characteristics.

<R> TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



<R> NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering

Peak reflow temperature 260°C or below (package surface temperature)

Time of peak reflow temperature 10 seconds or less Time of temperature higher than 220°C 60 seconds or less

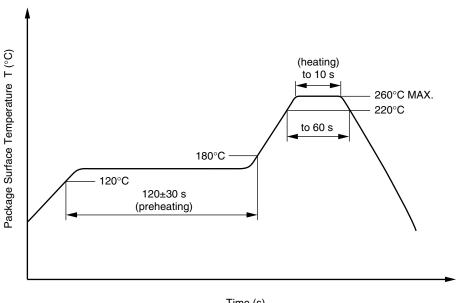
Time to preheat temperature from 120 to 180°C 120±30 s Number of reflows Three

Flux Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

Temperature 260°C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine Flux

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature) 350°C or below

Time (each pins)

Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

 Fluxes Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1 μ F is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Avoid storage at a high temperature and high humidity.

<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Maximum repetitive peak operating isolation voltage	U _{IORM}	707	V_{peak}
Partial discharge test voltage at 100% production test	U_pr	1 326	V_{peak}
U_{pr} = 1.875 × U_{IORM} , Method b, t_m =1sec, p_d < 5 pC			
Partial discharge test voltage at Type test and Sample test	U_pr	1 131	V_{peak}
$U_{pr} = 1.6 \times U_{IORM}$, Method a, $t_m = 10$ sec, $p_d < 5$ pC			
Maximum transient isolation voltage (Transient overvoltage t _{ini} =60sec)	U _{IOTM}	6 000	V_{peak}
Installation classification (IEC 60664/ DIN EN 60664-1/ VDE0110 Part 1)			
for rated mains voltage < 300 Vr.m.s.		I - IV	
for rated mains voltage ≤ 600 Vr.m.s.		I - III	
Comparative tracking index (IEC 60112/ DIN EN 60112/ VDE 0303 Part 11)	CTI	175	
Material group (DIN EN 60664-1/ VDE0110 Part 1)		III a	
Pollution degree (DIN EN 60664-1/ VDE0110 Part 1)		2	
Climatic category (IEC 60068-1/ DIN EN 60068-1)		40/110/21	
Operating temperature range	T _A	-40 to +110	°C
Storage temperature range	T_{stg}	-55 to +125	°C
Isolation resistance, minimum value			
V_{IO} = 500 Vdc at T_A =25°C	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 Vdc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety limiting values ratings (maximum allowable in the event of a fault			
or a failure, see thermal derating curve)			
Maximum ambient safety temperature	Ts	150	°C
Maximum input current	Isi	200	mA
Maximum output power	Pso	300	mW
Isolation resistance at V _{IO} = 500 Vdc, T _A =Ts	Ris MIN.	10 ⁹	Ω

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

Revision History

PS9124 Data Sheet

•		Description		
Rev.	Date	Page	Summary	
0.01	Jul 03, 2012	_	First edition issued	
1.00	Aug 30, 2013	Throughout	"Preliminary Data Sheet" is changed to "Data Sheet."	
		p.1	Modification of FEATURES	
			Modification of APPLICATIONS	
		p.6	Modification of Test circuit for propagation delay time	
		p.7 to 9	Addition of TYPICAL CHARACTERISTICS	
		p.10	Modification of TAPING SPECIFICATIONS	
		p.12	Addition of NOTES ON HANDLING	
		p.14	Addition of SPECIFICATION OF VDE MARKS LICENSE DOCUMENT	

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